2SB0950, 2SB0950A (2SB950, 2SB950A)

Silicon PNP epitaxial planar type Darlington

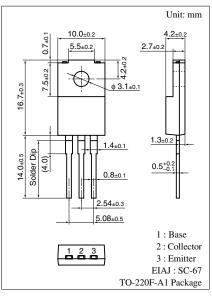
For power amplification and switching Complementary to 2SD1276 and 2SD1276A

■ Features

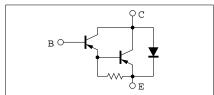
- High forward current transfer ratio h_{FE}
- High-speed switching
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter		Symbol	Rating	Unit
Collector to base	2SB0950	V_{CBO}	-60	V
voltage	2SB0950A		-80	
Collector to	2SB0950	V_{CEO}	-60	V
emitter voltage	2SB0950A		-80	
Emitter to base voltage		V_{EBO}	-5	V
Peak collector current		I_{CP}	-8	A
Collector current		I_C	-4	A
Collector power	$T_C = 25^{\circ}C$	P_{C}	40	W
dissipation	$T_a = 25^{\circ}C$		2	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C



Internal Connection



■ Electrical Characteristics $T_C = 25$ °C

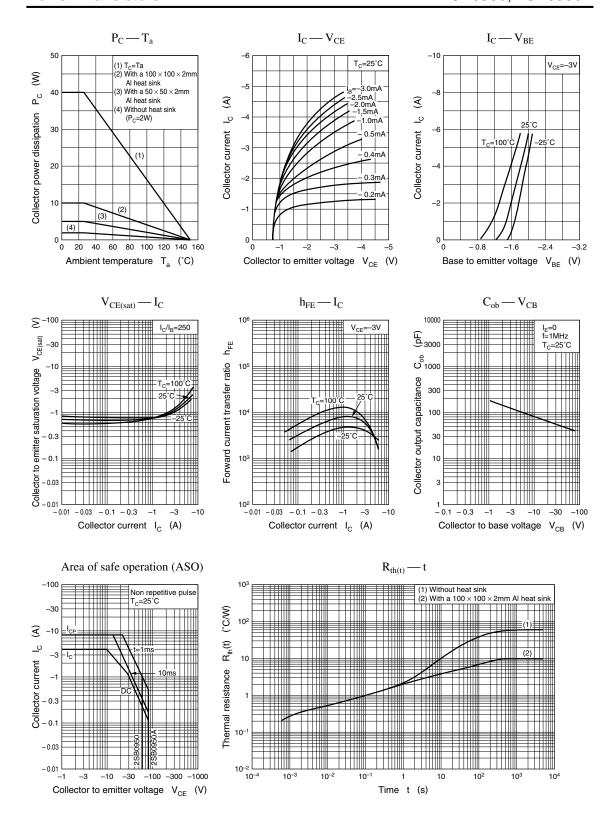
Paramete	r	Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SB0950	I_{CBO}	$V_{CB} = -60 \text{ V}, I_E = 0$			-200	μΑ
current	2SB0950A		$V_{CB} = -80 \text{ V}, I_E = 0$			-200	
Collector cutoff	2SB0950	I_{CEO}	$V_{CE} = -30 \text{ V}, I_{B} = 0$			-500	μΑ
current	2SB0950A		$V_{CE} = -40 \text{ V}, I_{B} = 0$			-500	
Emitter cutoff current	•	I_{EBO}	$V_{EB} = -5 \text{ V}, I_C = 0$			-2	mA
Collector to emitter	2SB0950	V _{CEO}	$I_{\rm C} = -30 \text{ mA}, I_{\rm B} = 0$	-60			V
voltage	2SB0950A			-80			
Forward current transfer ratio		h _{FE1}	$V_{CE} = -3 \text{ V}, I_C = -0.5 \text{ A}$	1 000			
		h _{FE2} *	$V_{CE} = -3 \text{ V}, I_{C} = -3 \text{ A}$	2 000		10 000	
Base to emitter voltage	;	V_{BE}	$V_{CE} = -3 \text{ V}, I_{C} = -3 \text{ A}$			-2.5	V
Collector to emitter satu	ration voltage	V _{CE(sat)1}	$I_C = -3 \text{ A}, I_B = -12 \text{ mA}$			-2	V
		V _{CE(sat)2}	$I_{\rm C} = -5 \text{ A}, I_{\rm B} = -20 \text{ mA}$			-4	V
Transition frequency		f_T	$V_{CE} = -10 \text{ V}, I_{C} = -0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time		t _{on}	$I_C = -3 \text{ A}, I_{B1} = -12 \text{ mA}, I_{B2} = 12 \text{ mA},$		0.3		μs
Storage time		t _{stg}	$V_{CC} = -50 \text{ V}$		2		μs
Fall time		$t_{\rm f}$			0.5		μs

Note) *: Rank classification

Rank	Q	Р		
h _{FE2}	2 000 to 5 000	4 000 to 10 000		

Note.) The Part numbers in the Parenthesis show conventional part number.

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